



# DATA SHEET

## SB620~SB660

### SCHOTTKY BARRIER RECTIFIERS

<b>VOLTAGE</b>	<b>20 to 60 Volts</b>	<b>CURRENT</b>	<b>6.0 Ampers</b>	<b>TO-220AC</b>	<b>Unit : inch (mm)</b>
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#### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O utilizing Flame Retardant Epoxy Molding Compound.
- Exceeds environmental standards of MIL-S-19500/228
- Low power loss, high efficiency.
- Low forward voltage, high current capability
- High surge capacity.
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.
- Both normal and Pb free product are available :  
Normal : 80~95% Sn, 5~20% Pb  
Pb free: 98.5% Sn above

#### MECHANICAL DATA

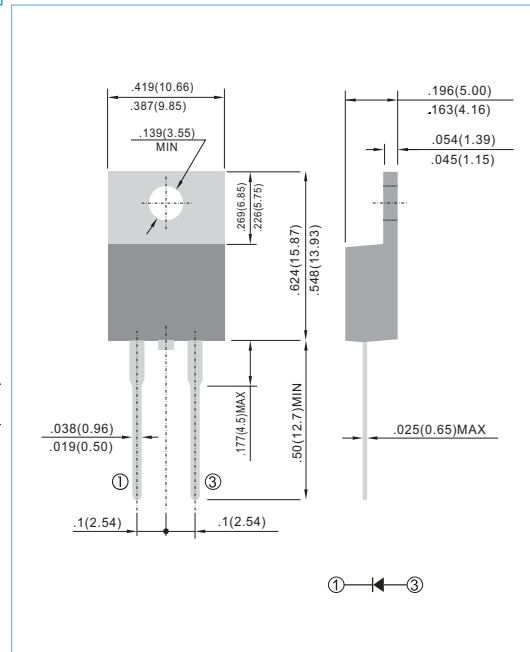
Case: TO-220AC full molded plastic package

Terminals: Lead solderable per MIL-STD-202, Method 208

Polarity: As marked.

Mounting Position: Any

Weight: 0.08 ounces, 2.24grams.



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

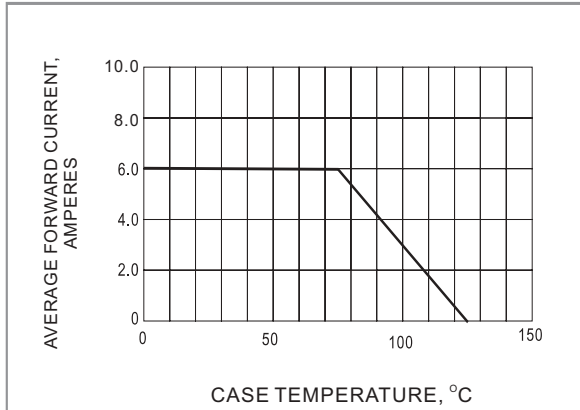
PARAMETER	SYMBOL	SB620	SB630	SB640	SB650	SB660	UNITS
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	V
Maximum Average Forward Current .375" (9.5mm) lead length at $T_c = 75^\circ C$	$I_{AV}$	6.0					A
Peak Forward Surge Current :8.3ms single half sine-wave superimposed on rated load(JEDEC method)	$I_{FSM}$	75					A
Maximum Forward Voltage at 6.0A	$V_F$	0.55			0.70		V
Maximum DC Reverse Current $T_c=25^\circ C$ at Rated DC Blocking Voltage $T_c=100^\circ C$	$I_R$	0.2			15		mA
Typical Thermal Resistance	$R_{\theta JC}$ $R_{\theta JA}$	6			80		$^\circ C / W$
Operating Junction Temperature Range	$T_J$	-50 to +125					$^\circ C$
Storage Temperature Range	$T_J, T_{STG}$	-50 to +150					$^\circ C$

#### NOTES:

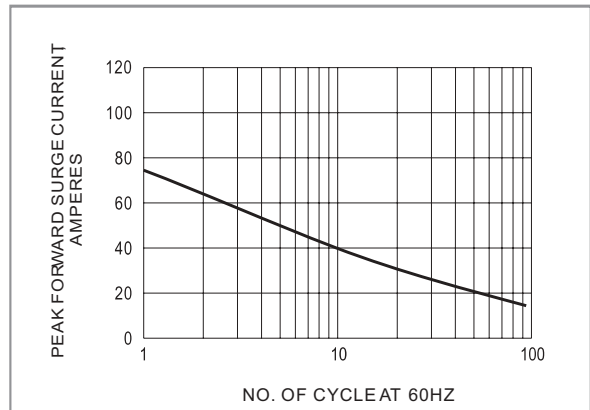
Both Bonding and Chip structure are available.



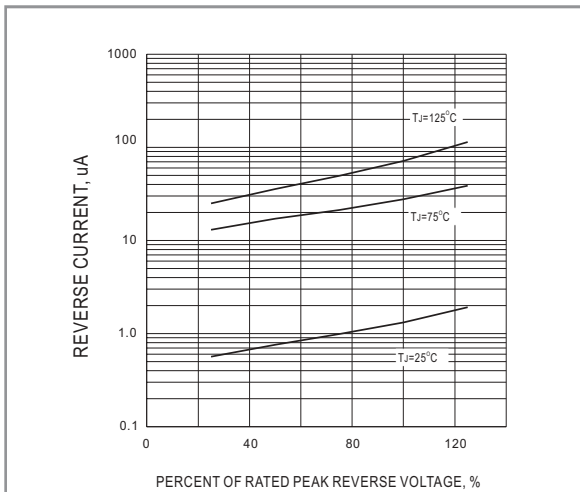
**RATING AND CHARACTERISTIC CURVES**



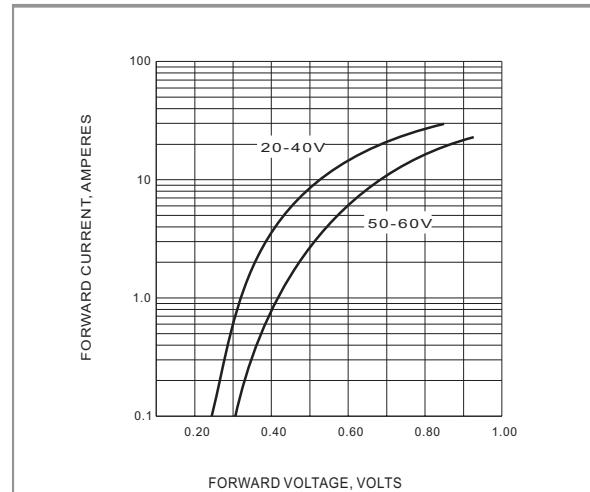
**Fig. 1- FORWARD CURRENT DERATING CURVE**



**Fig. 2- MAXIMUM NON-REPETITIVE SURGE CURRENT**



**Fig. 3- TYPICAL REVERSE CHARACTERISTIC**



**Fig. 4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC**